



MAINTENANCE MANUAL

LOGIC BOARD 19D901690G5

FOR MVS

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DESCRIPTION

The Logic Board (A1) controls the main operation of the MVS radio.

It is located in the bottom of the frame assembly underneath the Audio Board. Refer to the combination manual for a complete mechanical layout of the board. Figure 1 provides a Block Diagram of the Logic Board. Refer to the Table of Contents in this publication for IC data sheets with pinout information on integrated circuits and modules.

The Logic Board contains a microprocessor and associated memory circuits which include an EPROM for controlling the processor and a programmable "personality" EEPROM to store customer frequencies, tones and options. Programmable data is entered using an IBM compatible personal computer and a RS-232 interface. Refer to the programming manual for programming instructions.

CIRCUIT ANALYSIS

MICROPROCESSOR

Microprocessor U701 is an 8-bit processor that performs the logic functions to provide the control signals required in the radio. An external 11.0592 MHz crystal (Y701)

is used for the clock. The microprocessor controls the following:

- Synthesizer
- Transmit circuit
- Decoding of Channel Guard (tone or digital) and Type 99 tones
- Generation of Channel Guard (tone or digital)
- Transmitter and receiver audio mute gates.

Serial data at a 300 baud rate is used for communication between the microprocessor and the Front Cap Assembly. U701 uses the KEYPAD SERIAL line to receive Control Panel commands from the microprocessor in the Front Cap Assembly. U701 sends data back on the DISPLAY SERIAL line to update the LCD. Both serial lines normally rest at 5 volts with the data causing the lines to go low.

Diodes D701-D708 on $\overline{\text{PTT}}$, the serial lines, and $\overline{\text{AUDIO MUTE}}$ protect the microprocessor from static discharges. These lines are pulled high to +5 volts through 50K ohm resistors inside the microprocessor.

ERASABLE PROM (EPROM)

EPROM U703 is a CMOS 8K byte device with an internal address latch. All information required by the microprocessor for system operation resides in this EPROM.

ELECTRICALLY ERASABLE PROM (EEPROM)

EEPROM U704 is a 512 x 8-bit memory device, designated the "personality" PROM. This personality PROM stores all required customer information which includes: Frequencies, Tones, and Options. The EEPROM also retains the status of all radio functions (channel selection, volume setting, scan channel list, and scan on-off function) to return the radio to the same mode of operation after power is turned off or removed from the radio.

DC power for U704 is switched by transistor Q705. During the active high reset pulse to the microprocessor, Q705 removes +5 Vdc from U704 to reset the EEPROM. See the voltage regulator description below.

The EEPROM can be conveniently programmed without any need for opening up the radio. This is accomplished through the microphone jack (J725). The serial data is routed through the Control Board to the EEPROM on the Logic Board.

For an optional 128 channel radio, U704 is replaced with a larger memory (2048 x 8-bit) EEPROM device (19A705553P1).

LATCH

Latch U702 is a CMOS, 3-state, non-inverting, D type flip-flop with the following functions.

- To activate the band switch on the RF Board (if used).
- To function as a digital-to-analog converter (DAC) by generating sine wave signalling tones using resistor network R704.
- To activate the FAST SQUELCH on the Audio Board.
- To activate the low pass filter bypass on the Audio Board when Type 99 tone signalling is used.

RELAY

The relay circuit consists of NPN buffer transistor Q701 and NPN relay driver transistor Q702. The relay is activated by the microprocessor when a Type 99 call is received,

or when the public address option is enabled and the mic PTT is keyed. The circuit is capable of handling up to 150 milliamperes from an externally connected relay coil.

VOLTAGE REGULATOR

Voltage regulator U705 supplies a regulated +5 VDC to the microprocessor, the EPROM, the EEPROM and the latch circuit. A reset circuit is built into U705 to provide the microprocessor with a reset signal required during its power-up routine. A +8 volts regulated DC is supplied to regulator U705 from the 8 volt regulator U102, located on the RF Board.

BATTERY VOLTAGE FILTER

Transistor Q703 is a filter circuit for the switched A+ battery voltage. This circuit is used to reduce "alternator whine" interference. SW A+ filtered (13 volts) is used on the Audio Board.

CAUTION



The CMOS Integrated Circuit devices used in this equipment can be destroyed by static discharges. Before handling one of these devices, the serviceman should discharge himself by touching the case of a bench test instrument that has a 3-prong power cord connected to an outlet with a known good earth ground. When soldering or desoldering a CMOS device, the soldering iron should also have a 3-prong power cord connected to an outlet with a known good earth ground. A battery operated soldering iron may be used in place of the regular soldering iron.

SERVICE NOTES

If a faulty Logic Board is suspected it may be useful to confirm this by substitution of a known good board.

DC CHECKS

Power for the Logic Board is supplied by the 8 volts on J702, Pin 3. This comes from the transmitter regulator U102.

1. Check for +5 volts ± 0.25 volts on U705, Pin 5.
2. Check Power-On Reset on U701, Pin 9 (see Figure 2). If not present, check regulator U705, Pin 2 and transistor Q704.

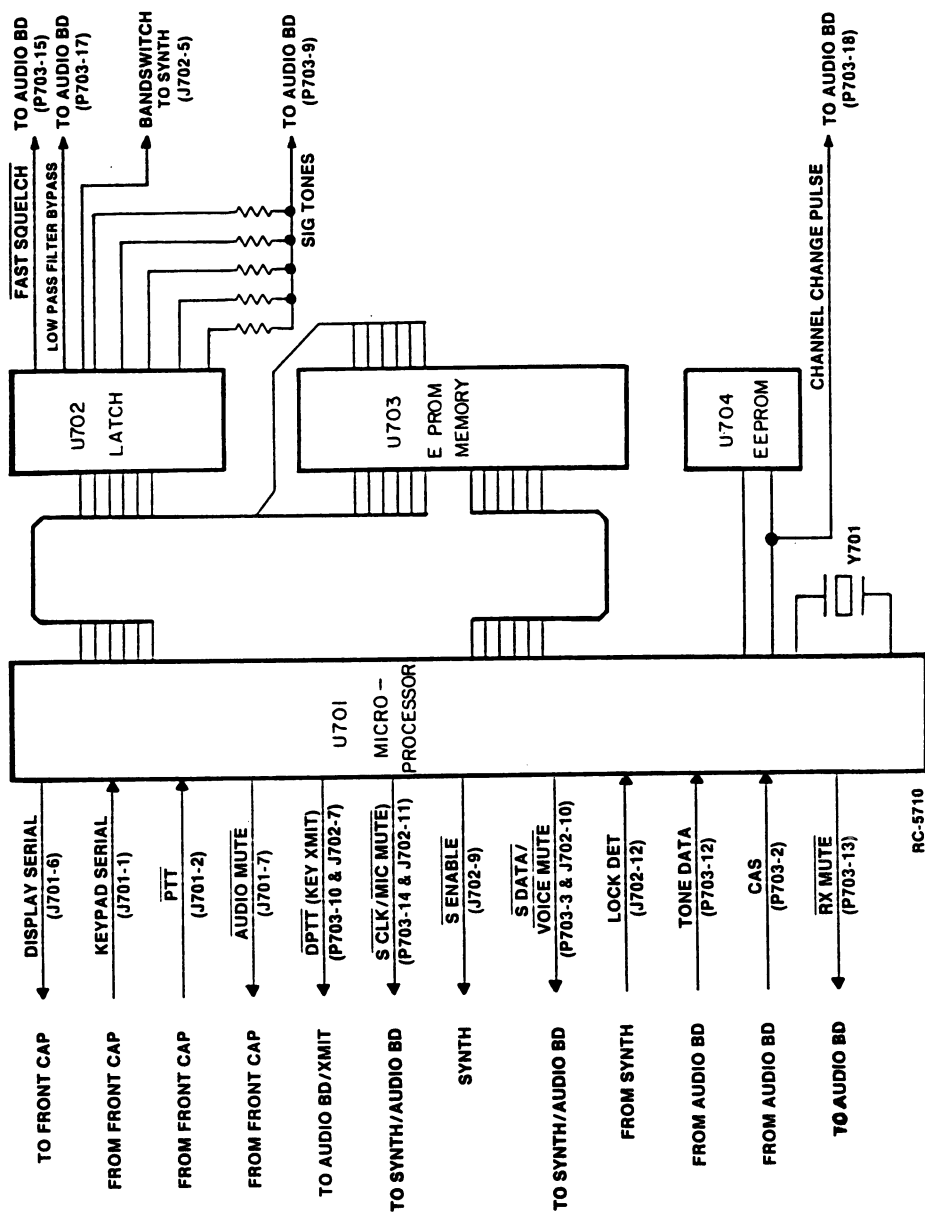


FIGURE 1 - BLOCK DIAGRAM

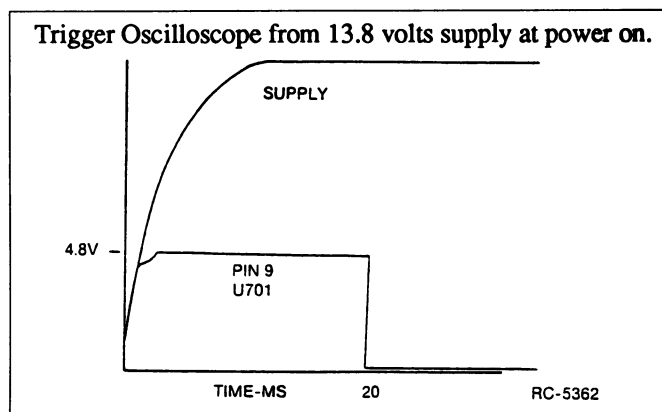


FIGURE 2 - RESET WAVEFORM

3. Check for oscillator activity by examining the ALE clock on U701, Pin 30 (see Figure 3). If not present, examine the system clock on U701, Pin 18 (5 volts pp at 11.059 MHz). The presence of the system clock, but no ALE may indicate a bad U701. If the system clock is not present, suspect Y701 and related components.

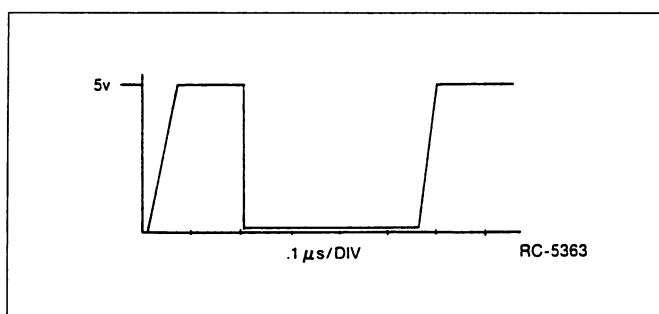


FIGURE 3 - ALE CLOCK

4. All output lines from the microprocessor are pulled high to +5 volts through 50K ohm resistors inside the microprocessor. If a line is high, you may ground that pin and monitor the results. However, if a line is low, the line may not be forced to +5 volts.

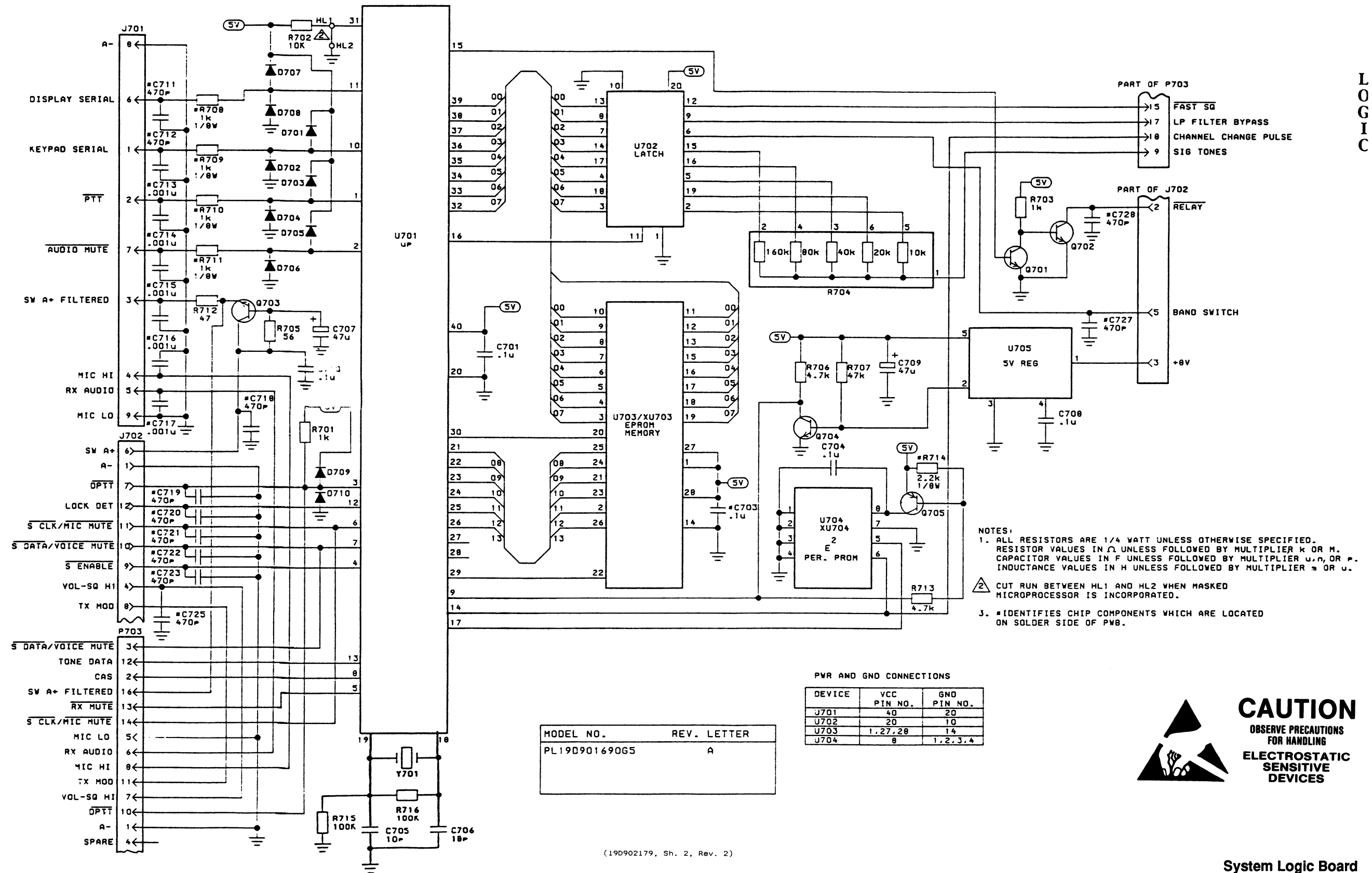


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General Electric Company
Lynchburg, Virginia 24502

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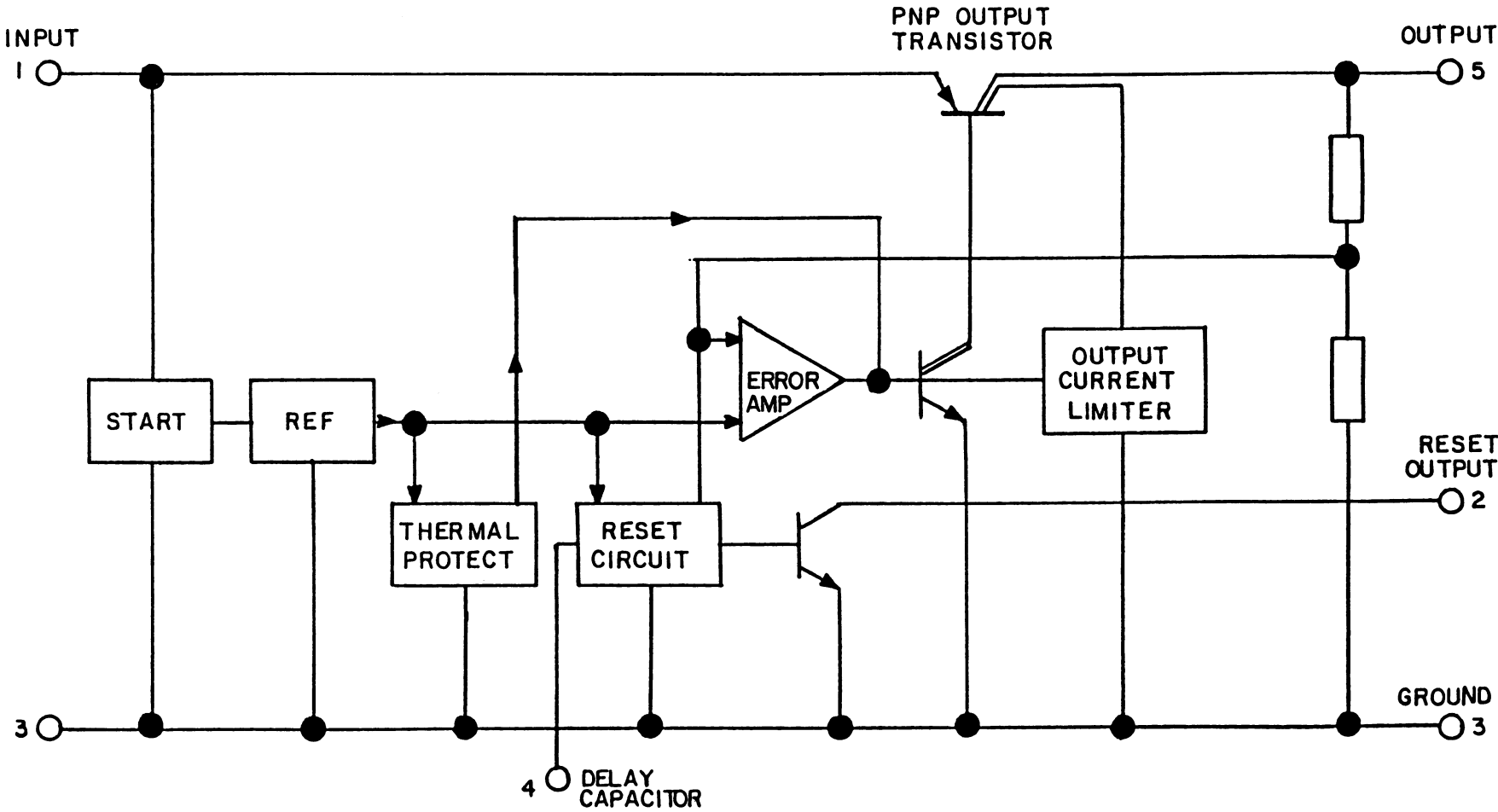
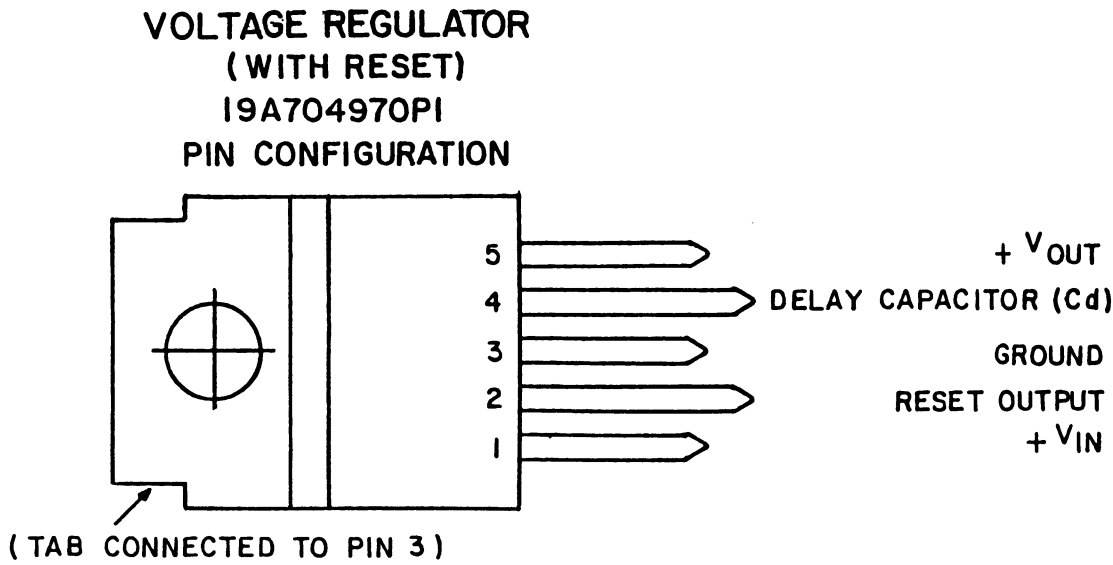
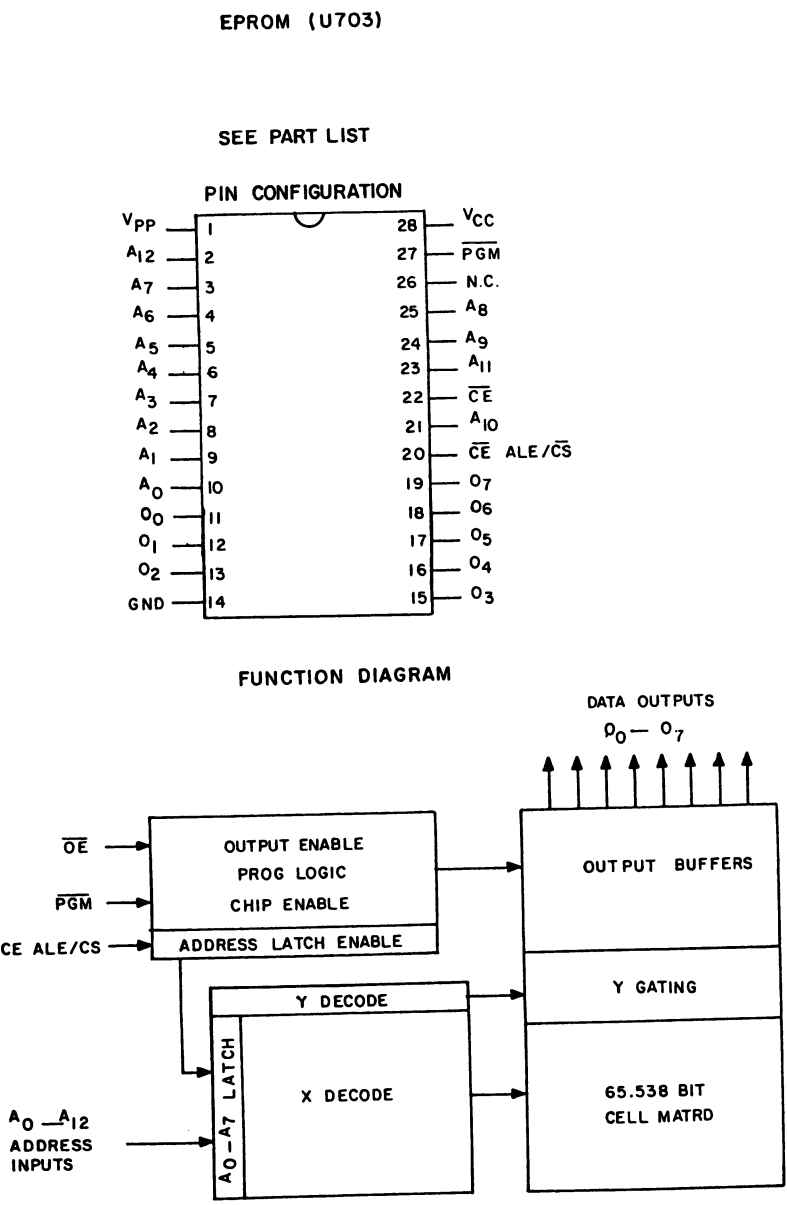
CAUTION
OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

System Logic Board

PARTS LIST			SYMBOL	GE PART NO.	DESCRIPTION
MVS LOGIC BOARD 19D901690G5 ISSUE 1			R713	H212CRP247C	Deposited carbon: 4.7K ohms + or -5%, 1/4 w.
			R714	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8 w.
			R715 and R716	19B800607P104	Metal film: 100K ohms + or - 5%, 200 VDCW, 1/8 w.
					- - - - - INTEGRATED CIRCUITS - - - - -
			U701	19A703714P1	Microcomputer: HMOS, 8-BIT.
			U702	19A704380P12	Digital: sim to: 74HC374.
			U703	19A705561G3	Programmable Memory.
			U704	19A704724P1	Digital: EE PROM; sim to XICOR X2404P.
			U705	19A704970P1	Voltage Regulator, 5 volts; sim to: SGS L387.
					- - - - - SOCKETS - - - - -
			XU703	19A700156P3	Integrated circuit: 28 contacts; sim to AMP 640362P3.
			XU704	19A700156P15	Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.
					- - - - - CRYSTALS - - - - -
			Y701	19A702511G15	Quartz: 11.059200 MHz.
					- - - - - MISCELLANEOUS - - - - -
				19B800608P156	Rivet Tube.

SYMBOL	GE PART NO.	DESCRIPTION
- - - - - CAPACITORS - - - - -		
C701	19A700121P106	Ceramic: 0.1 uF + or -20%, 50 VDCW.
C703	19A702052P26	Ceramic: 0.1 uF + or - 10%, 50 VDCW.
C704	19A700121P106	Ceramic: 0.1 uF + or -20%, 50 VDCW.
C705	19A700235P13	Ceramic: 10 pF + or -5%, 50 VDCW.
C706	19A700235P16	Ceramic: 18 pF + or -5%, 50 VDCW.
C707	19A704879P2	Electrolytic: 47 uF + or -20%, 16 VDCW.
C708	T644ACP410K	Polyester: 0.1 uF + or -10%, 50 VDCW.
C709	19A701534P9	Tantalum: 47 uF + or -20%, 6.3 VDCW.
C710	19A700121P106	Ceramic: 0.1 uF + or -20%, 50 VDCW.
C711 and C712	19A702061P77	Ceramic: 470 pF + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.
C713 thru C717	19A702052P5	Ceramic: 1000 pF + or -10%, 50 VDCW.
C718 thru C720	19A702061P77	Ceramic: 470 pF + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.
C721 thru C723	19A702061P61	Ceramic: 100 pF + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.
C725	19A702061P77	Ceramic: 470 pF + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.
C727 and C728	19A702061P77	Ceramic: 470 pF + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.
- - - - - DIODES - - - - -		
D701 thru D710	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.
- - - - - JACKS - - - - -		
J701	19B209727P29	Connector.
J702	19A704779P11	Connector: sim to Molex 22-17-2122.
- - - - - PLUGS - - - - -		
P703	19A704874P1	Connector: sim to: Elco 00-9021-18-12-00-339.
- - - - - TRANSISTORS - - - - -		
Q701	19A700023P2	Silicon, NPN: sim to 2N3904.
Q702 and Q703	19A702503P2	Silicon, NPN.
Q704	19A700023P2	Silicon, NPN: sim to 2N3904.
Q705	19A700022P2	Silicon, PNP: sim to 2N3906.
- - - - - RESISTORS - - - - -		
R701	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.
R702	H212CRP310C	Deposited carbon: 10K ohms + or - 5%, 1/4 w.
R703	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.
R704	19A704885P5	Resistive Network: + or -2%, 1/8 w.
R705	H212CRP056C	Deposited carbon: 56 ohms + or -5%, 1/4 w.
R706	H212CRP247C	Deposited carbon: 4.7K ohms + or -5%, 1/4 w.
R707	H212CRP347C	Deposited carbon: 47K ohms + or -5%, 1/4 w.
R708 thru R711	19B800607P102	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.
R712	H212CRP047C	Deposited carbon: 47 ohms + or -5%, 1/4 w.

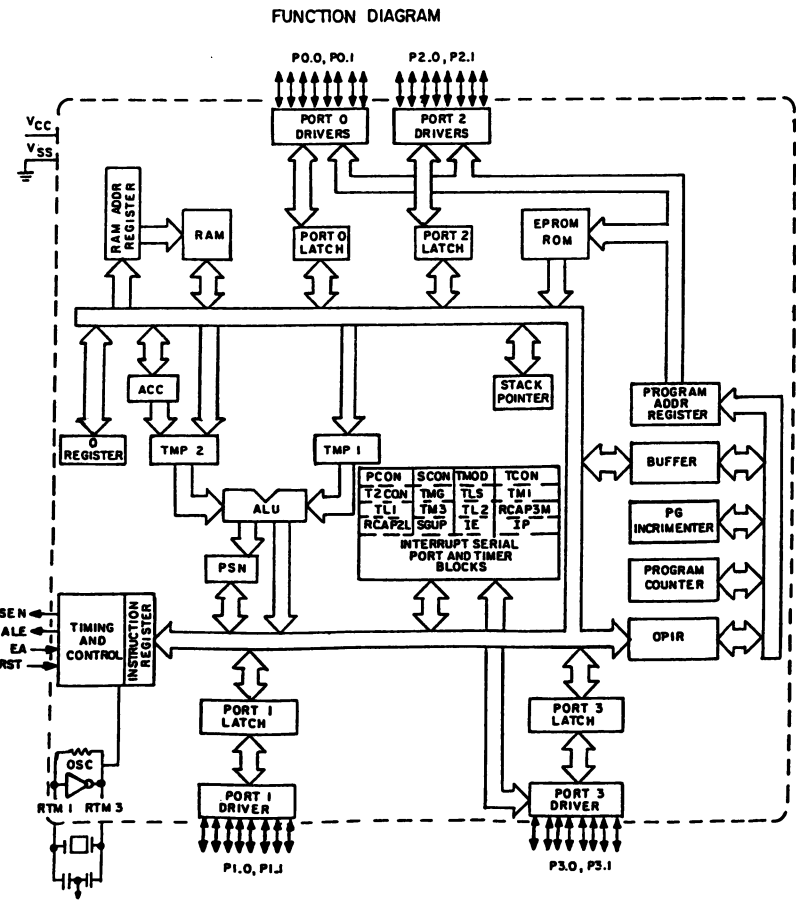
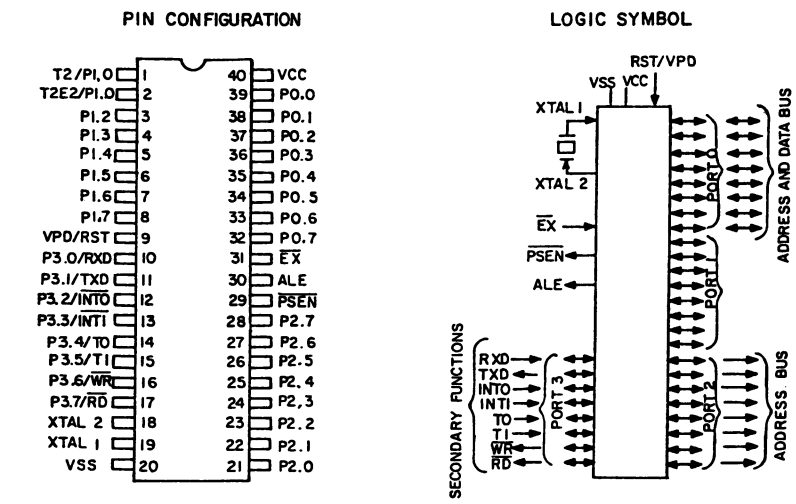
*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES



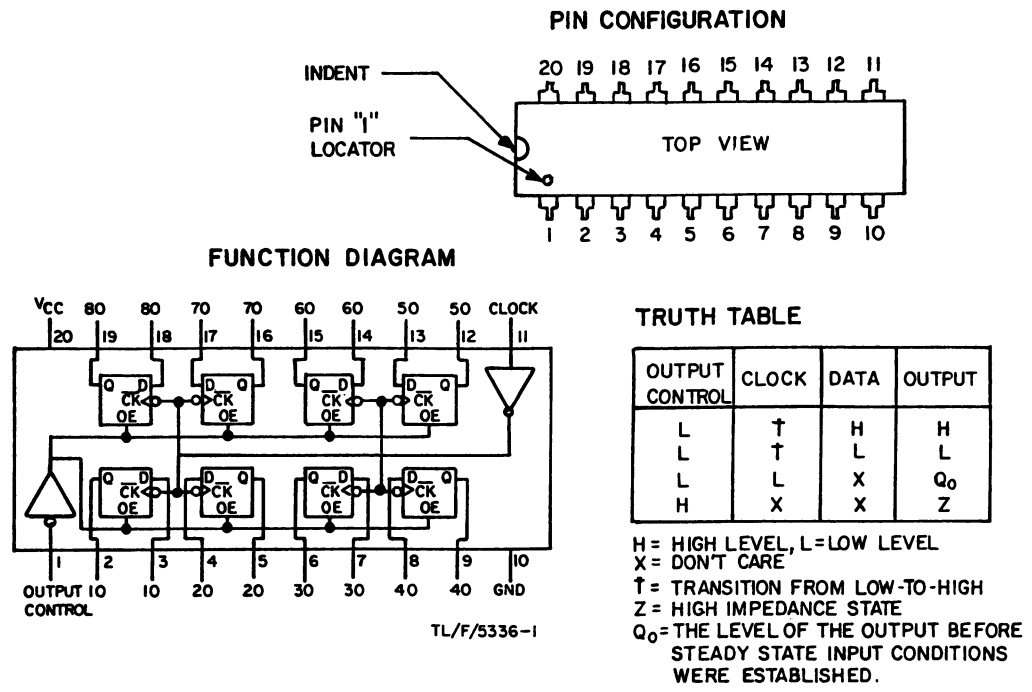
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C

HMOS 8-BIT MICROPROCESSOR (U701)
19A703714P1



OCTAL 3- STATE D FLIP FLOP (U702)
19A704380P12 (74HC374)



DIGITAL 512 X8 EEPROM
19A704724P1
(U704)

